CNA4302A

Integrated Photosensors

Object Detection, Contactless Switch

■ Features

- Highly precise position detection (Slit width: 0.3 mm)
- Gap width: 1.2 mm
- High response: $t_{PHL} = 3 \mu s$, $t_{PLH} = 8 \mu s$ (typ.)
- With a positioning pins

■ Absolute Maximum Ratings $T_a = 25$ °C±3°C

Parameter		Symbol	Rating	Unit	
Input	Reverse voltage	V_R	6	V	
	Forward current	I_{F}	50	mA	
	Power dissipation *1	P _D	75	mW	
Output	Opelation Supply voltage	V _{CC} 7		V	
	Output votage	V _O	12	V	
	Output current	I_{OUT}	8	mA	
	Collector power dissipation *2	$P_{\rm C}$	80	mW	
Temperature	Operating ambient temperature	T _{opr}	-25 to +85	°C O	
	Storage temperature	T _{stg}	-40 to +100	OC (

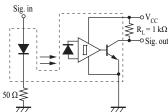
Note) *1: Input power derating ratio is 1.0 mW/°C at $T_a \ge 25$ °C

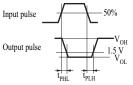
■ Electrical Characteristics T_a = 25°C±3°C

	Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input Characteristics	Forward votage	$V_{\rm F}$	$I_F = 20 \text{ mA}$		1.2	1.4	V
	Reverse current	I_R	$V_R = 3 V$	00)		10	μΑ
Output Characteristics	Supply voltage	V _{CC}	9:00 013:10 CO	2.2		7.0	V
	Low level output voltage	V_{OL}	$V_{CC} = 5 \text{ V}, I_{OL} = 5 \text{ mA}, I_F = 2 \text{ mA}$		0.15	0.4	V
	High level output current	I_{OH}	$V_{CC} = 5 \text{ V}, V_{OH} = 12 \text{ V}, I_F = 0 \text{ mA}$			100	μΑ
	Low level supply current	I_{CCL}	$V_{CC} = 5 \text{ V}, I_F = 2 \text{ mA}$		0.8	2.0	mA
	High level supply current	I_{CCH}	$V_{CC} = 5 \text{ V}, I_F = 0 \text{ mA}$		0.8	2.0	mA
Transfer Characteristics	High → Low threshold input current	I_{FHL}	$V_{\rm CC} = 5.0 \mathrm{V}$			1.60	mA
	Hysteresis	$\rm I_{FLH}/\rm I_{FHL}$	$V_{\rm CC} = 5.0 \mathrm{V}$		0.88		_
	Propagation delay time (High→Low)*	t _{PHL}	V -5 V D -11rO I -2 mA		3.0		μs
	Propagation delay time (Low→High) *	$t_{\rm PLH}$	$V_{CC} = 5 \text{ V}, R_L = 1 \text{ k}\Omega, I_F = 2 \text{ mA}$		8.0		

Note) 1. Input and output are practiced by electricity.

- 2. This device is designed by disregarding for radiation.
- 3. *: Propagation delay time measuring circuit



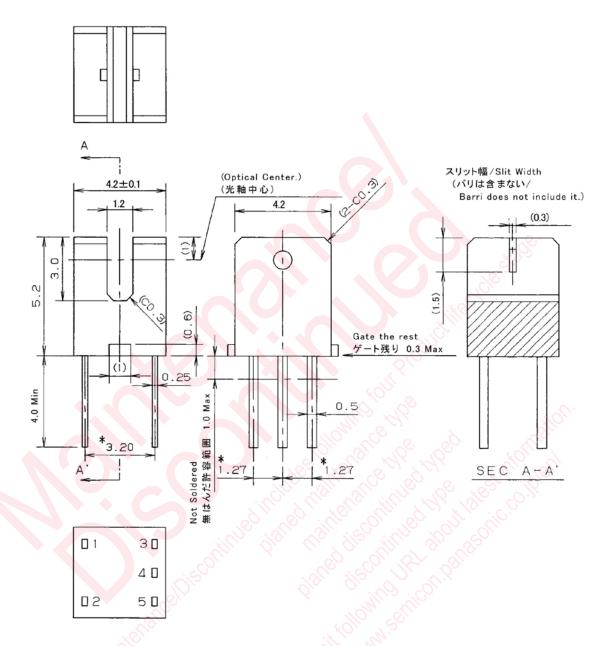


 t_{PHL} : Propagation delay time (High \rightarrow Low) t_{PLH} : Propagation delay time (Low \rightarrow High)

^{*2:} Output power derating ratio is 1.07 mW/°C at $T_a \ge 25$ °C

CNA4302A Panasonic

■ Package (Unit: mm)



• Pin name

Anode
 V_O
 Cathode
 GND

3. V_{CC}

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